# Switch Mode Power Rectifiers

These state-of-the-art devices are a series designed for use in switching power supplies, inverters and as free wheeling diodes.

#### Features

- Ultrafast 35 and 60 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 V
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- These are Pb–Free Devices\*
- **Mechanical Characteristics:**
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



#### **ON Semiconductor®**

www.onsemi.com

### ULTRAFAST RECTIFIERS 16 AMPERES, 100–600 VOLTS





#### MARKING DIAGRAM



A = Assembly Location

- Y = Year WW = Work Week
- U16xx = Device Code
  - xx = 10, 15, 20, 40 or 60
- G = Pb-Free Package
- KA = Diode Polarity

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

#### MAXIMUM RATINGS

Rating		Symbol	10CT	15CT	20CT	40CT	60CT	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	150	200	400	600	V	
Average Rectified Forward Current Total Device, (Rated V <sub>R</sub> ), T <sub>C</sub> = 150°C	Per Leg Total Device	I <sub>F(AV)</sub>	8.0 16			A			
Peak Rectified Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz), T <sub>C</sub> = 150°C	Per Diode Leg	I <sub>FM</sub>	16					A	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I <sub>FSM</sub>	100					A	
Operating Junction Temperature and Storage Temperature		T <sub>J</sub> , T <sub>stg</sub>	-65 to +175					°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS (Per Diode Leg)

Parameter	Symbol	Value	Unit	
Maximum Thermal Resistance, Junction-to-Case	$R_{\thetaJC}$	3.0	2.0	°C/W

#### ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	1620	1640	1660	Unit
Maximum Instantaneous Forward Voltage (Note 1) ( $i_F = 8.0 \text{ A}, T_C = 150^{\circ}\text{C}$ ) ( $i_F = 8.0 \text{ A}, T_C = 25^{\circ}\text{C}$ )	VF	0.895 0.975	1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_C = 150^{\circ}C$ ) (Rated DC Voltage, $T_C = 25^{\circ}C$ )	i <sub>R</sub>	250 5.0	500 10		μΑ
Maximum Reverse Recovery Time $(I_F = 1.0 \text{ A}, \text{ di/dt} = 50 \text{ A/}\mu\text{s})$ $(I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{REC} = 0.25 \text{ A})$	t <sub>rr</sub>	35 25	60 50		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width =  $300 \,\mu$ s, Duty Cycle  $\leq 2.0\%$ 

#### MUR1610CT, MUR1615CT, MUR1620CT



#### MUR1640CT



#### MUR1660CT









Figure 17. Typical Capacitance, Per Leg

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MUR1610CTG	TO-220 (Pb-Free)	
MUR1615CTG	TO-220 (Pb-Free)	
MUR1620CTG	TO-220 (Pb-Free)	50 Units / Rail
MUR1640CTG	TO-220 (Pb-Free)	
MUR1660CTG	TO-220 (Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

S

# onsemi

		TO-220 CASE 221A ISSUE AK						DATE	13 JAN 2022
SCALE 1:1			1. C 2. C 3. C	CONTR DIMEN LEAD	ROLLING DI ISION Z DEI D IRREGULA	MENSION FINES A ZO ARITIES AR	ONE WHERE AL E ALLOWED.		
			4. N	лах м	VIDTHFOR	F102 DEV	ICE = 1.35MM		
			Г		INC	HES	MILLIM	ETERS	
				ым 🛛	MIN.	MAX.	MIN.	MAX.	
	2 3			A	0.570	0.620	14.48	15.75	
				в	0.380	0.415	9.66	10.53	
н —	₩₩			с	0.160	0.190	4.07	4.83	
	7 \7	H I		D	0.025	0.038	0.64	0.96	
z_				F	0.142	0.161	3.60	4.09	
<u> </u>	I K			G	0.095	0.105	2.42	2.66	
				н	0.110	0.161	2.80	4.10	
	Щ Щ <u> </u>	Ü I		J	0.014	0.024	0.36	0.61	
	Г <mark>і</mark>			к	0.500	0.562	12.70	14.27	
V — + I I-	►- <b>  </b> ``.			L	0.045	0.060	1.15	1.52	
G <del></del>	.  <mark> </mark> <sup></sup> J <sup>−</sup>			N	0.190	0.210	4.83	5.33	
· · · ·	- <b>→  </b> D			Q	0.100	0.120	2.54	3.04	
	N 🖛			R	0.080	0.110	2.04	2.79	
				s	0.045	0.055	1.15	1.41	
				т	0.235	0.255	5.97	6.47	
				U	0.000	0.050	0.00	1.27	
				V	0.045		1.15		
				Z		0.080		2.04	
2. 3. 4. STYLE 5: PIN 1. 2.	BASE         PIN 1.           COLLECTOR         2.           EMITTER         3.           COLLECTOR         4.           STYLE 6:         GATE           DRAIN         2.	EMITTER COLLECTOR EMITTER ANODE CATHODE	IN 1. CAT 2. ANO 3. GAT 4. ANO LE 7: IN 1. CAT 2. ANO	ode Te ode Thode ode		2. 3. 4. STYLE 8: PIN 1. 2.	MAIN TERMINAL MAIN TERMINAL GATE MAIN TERMINAL CATHODE ANODE	2	
4. STYLE 9: PIN 1.	DRAIN 4. STYLE 10 GATE PIN 1.	ANODE CATHODE GATE P SOURCE	3. CAT 4. ANO LE 11: IN 1. DR/ 2. SOU	ode Ain		4. STYLE 12: PIN 1.	EXTERNAL TRIP ANODE MAIN TERMINAL MAIN TERMINAL	. 1	
3.	EMITTER 3.	DRAIN SOURCE	3. GAT 4. SOL	ΤE		3.	GATE NOT CONNECTI		

 
 DOCUMENT NUMBER:
 98ASB42148B
 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

 DESCRIPTION:
 TO-220
 PAGE 1 OF 1

 onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

MUR1610CT MUR1610CTG MUR1615CT MUR1615CTG MUR1620CT MUR1620CTG MUR1640CT MUR1640CTG MUR1660CT MUR1660CTG MUR1660CT